

## MICROCIRCUIT DATA SHEET

Original Creation Date: 07/22/96 Last Update Date: 10/08/99 Last Major Revision Date: 09/01/99

## 1A LOW DROPOUT REGULATOR

MNLM2940-5.0-X REV 1A1

### General Description

The LM2940 positive voltage regulator features the ability to source 1A of ouput current with a dropout voltage of typically 0.5V and a maximum of 1V over the entire temperature range. Furthermore, a quiescent current reduction circuit has been included which reduces the ground current when the differential between the input voltage and the output voltage exceeds approximately 3V. The quiescent current with 1A of output current and an input-output differential of 5V is therefore only 30 mA. Higher quiescent currents only exist when the regulator is in the dropout mode (Vin - Vout  $\leq$  3V).

Designed also for vehicular applications, the LM2940 and all regulated circuitry are protected from reverse battery installations or 2-battery jumps. During line transients, such as load dump when the input voltage can momentarily exceed the specified maximum operating voltage, the regulator will automatically shut down to protect both the internal circuits and the load. The LM2940 cannot be harmed by temporary mirror-image insertion. Familiar regulator features such as short circuit and thermal overload protection are also provided.

### Industry Part Number

NS Part Numbers

LM2940

LM2940J-5.0/883 LM2940K-5.0/883 LM2940WG-5.0/883

Prime Die

LM2940

### Controlling Document

SEE FEATURES SECTION

### Processing

 ${\tt MIL-STD-883,\ Method\ 5004}$ 

### Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp	(°C)
1	Static tests at	+25	
2	Static tests at	+125	
3	Static tests at	-55	
4	Dynamic tests at	+25	
5	Dynamic tests at	+125	
6	Dynamic tests at	-55	
7	Functional tests at	+25	
8A	Functional tests at	+125	
8B	Functional tests at	-55	
9	Switching tests at	+25	
10	Switching tests at	+125	
11	Switching tests at	-55	

### Features

- Dropout voltage typically 0.5V @ Io = 1A
- Output current in excess of 1A
- Output voltage trimmed before assembly
- Reverse battery protection
- Internal short circuit current limit
- Mirror image insertion protection
- CONTROLLING DOCUMENT

LM2940J-5.0/883 5962-8958701EA LM2940K-5.0/883 5962-8958701YA LM2940WG5.0/883 5962-8958701XA

## (Absolute Maximum Ratings)

(Note 1)

```
Input Voltage (Survival Voltage ≤100ms)
                                                            607
Internal Power Dissipation
 (Note 2, 3)
                                                           Internally Limited
Maximum Junction Temperature
                                                           150 C
Storage Temperature Range
                                                            -65 C to +150 C
Lead Temperature
    (Soldering, 10 seconds)
                                                            300 C
Thermal Resistance
    ThetaJA
                                                             40 C/W
      T03 Pkg
                      (Still Air)
      T03 Pkg
                      (500LF/Min Air Flow)
                                                            TBD
      CERDIP
                      (Still Air)
                                                             73 C/W
      CERDIP
                      (500LF/Min Air Flow)
                                                             37 C/W
      CERAMIC SOIC
CERAMIC SOIC
                      (Still Air)
                                                           122 C/W
                      (500LF/Min Air Flow)
                                                             77 C/W
    ThetaJC
      T03
                                                             5 C/W
      CERDIP
                                                             3 C/W
     (Note 3)
      CERAMIC SOIC
                                                             5 C/W
     (Note 3)
Package Weight
      T03 Pkg
                                                            TBD
      CERDIP
                                                            1970mg
      CERAMIC SOIC
                                                             360mg
ESD Susceptibility
 (Note 4)
                                                            4000V
```

- Note 1: Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions see the Electrical Characteristics. The guaranteed specification apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by Tjmax (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is Pdmax = (Tjmax TA)/ThetaJA or the number given in the Absolute Maximum Ratings, whichever is lower.
- Note 3: The package material for these devices allows much improved heat transfer over our standard ceramic packages. In order to take full advantage of this improved heat transfer, heat sinking must be provided between the package base (directly beneath the die), and either metal traces on, or thermal vias through, the printed circuit board. Without this additional heat sinking, device power dissipation must be calculated using junction-to-ambient, rather than junction-to-case, thermal resistance. It must not be assumed that the device leads will provide substantial heat transfer out of the package, since the thermal resistance of the leadframe material is very poor, relative to the material of the package base. The stated junction-to-case thermal resistance is for the package material only, and does not account for the additional thermal resistance between the package base and the printed circuit board. The user must determine the value of the additional thermal resistance and must combine this with the stated value for the package, to calculate the total allowed power dissipation for the device.
- Note 4: Human body model, 100pF discharged through 1.5K Ohms

## Recommended Operating Conditions

(Note 1)

Input Voltage

26V

Operating Temperature Range

-55 C  $\leq$  TA  $\leq$  +125 C

Note 1: Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

## Electrical Characteristics

## DC PARAMETERS:

(The following conditions apply to all the following parameters, unless otherwise specified.) DC: Vin = 10V, Io = 1A, Cout = 22uF

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
Vout	Output Voltage	Vin = 10V, Io = 5mA			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 6V, Io = 5mA			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 7V, Io = 5mA			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 26V, Io = 5mA			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 10V, Io = 1A			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 6V, Io = 1A			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 6V, Io = 50mA			4.85	5.15	V	1
					4.75	5.25	V	2, 3
		Vin = 10V, Io = 50mA			4.85	5.15	V	1
					4.75	5.25	V	2, 3
	Reverse Polarity Input Voltage DC	Ro = 100 Ohms	1		-15		V	1, 2,
Iq	Quiescent Current	Vin = 10V, Io = 5mA			0	15	mA	1
					0	20	mA	2, 3
		Vin = 7V, Io = 5mA			0	15	mA	1
					0	20	mA	2, 3
		Vin = 26V, Io = 5mA			0	15	mA	1
					0	20	mA	2, 3
		Vin = 10V, Io = 1A			0	50	mA	1
					0	100	mA	2, 3
Vrline	Line Regulation	7V ≤ Vin ≤ 26V, Io = 5mA			-40	40	mV	1
					-50	50	mV	2, 3
Vrload	Load Regulation	Vin = 10V, 50mA ≤ Io ≤ 1A			-50	50	mV	1
					-100	100	mV	2, 3

## Electrical Characteristics

DC PARAMETERS: (Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.) DC: Vin = 10V, Io = 1A, Cout = 22uF

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
Vdo	Dropout Voltage	Io = 1A			0	0.7	V	1
					0	1	V	2, 3
		Io = 100mA			0	200	mV	1
					0	300	mV	2, 3
Isc	Short Circuit Current	Vin = 10V			1.5		A	1
					1.3		A	2, 3

## AC PARAMETERS:

(The following conditions apply to all the following parameters, unless otherwise specified.) AC: Vin = 10V, Io = 1A, Cout = 22uF

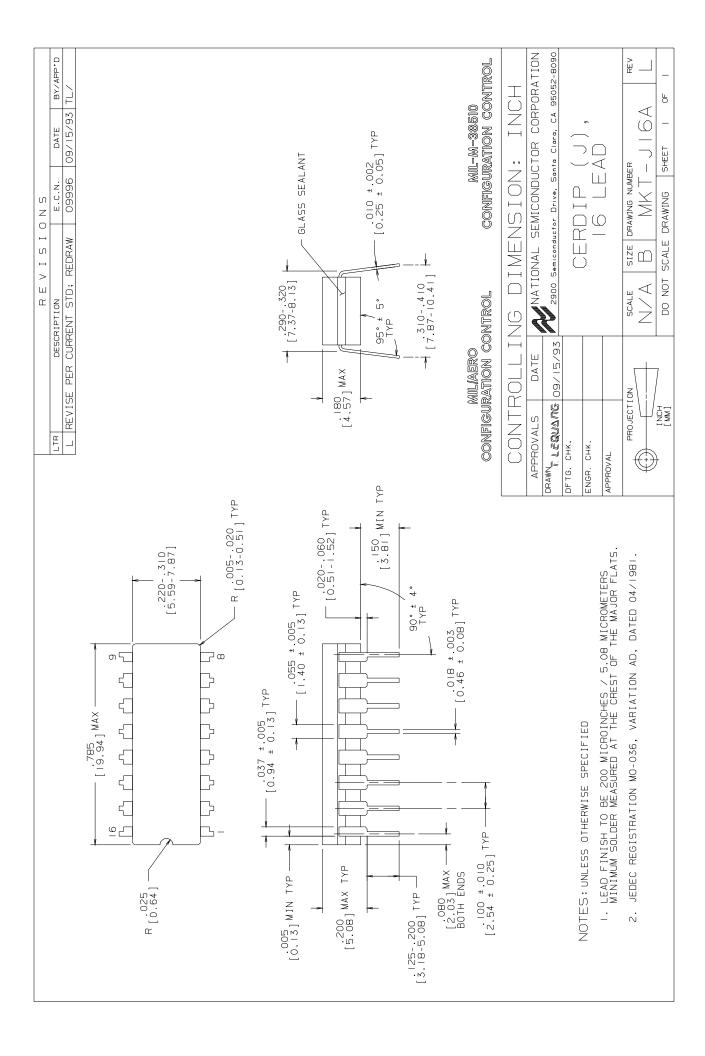
	Max Line Transient	Vo ≤ 6V, Ro = 100 Ohms, T = 20ms	1	40		V	7, 8A, 8B
	Reverse Polarity Input Voltage Transient	T = 20ms, Ro = 100 Ohms	1	-45		V	7, 8A, 8B
RR	Ripple Rejection	Vin = 10V, 1Vrms, f = 1KHz, Io = 5mA	1	60		dВ	4
			1	50		dВ	5, 6
No	Output Noise Voltage	Vin = 10V, Io = 5mA, 10Hz = 100KHz	1	0	700	uVrm	s 4, 5, 6
Zo	Output Impedance	Vin = 10V, Io = 100mA DC and 20mA AC, fo = 120Hz	1		1	Ohm	4, 5,

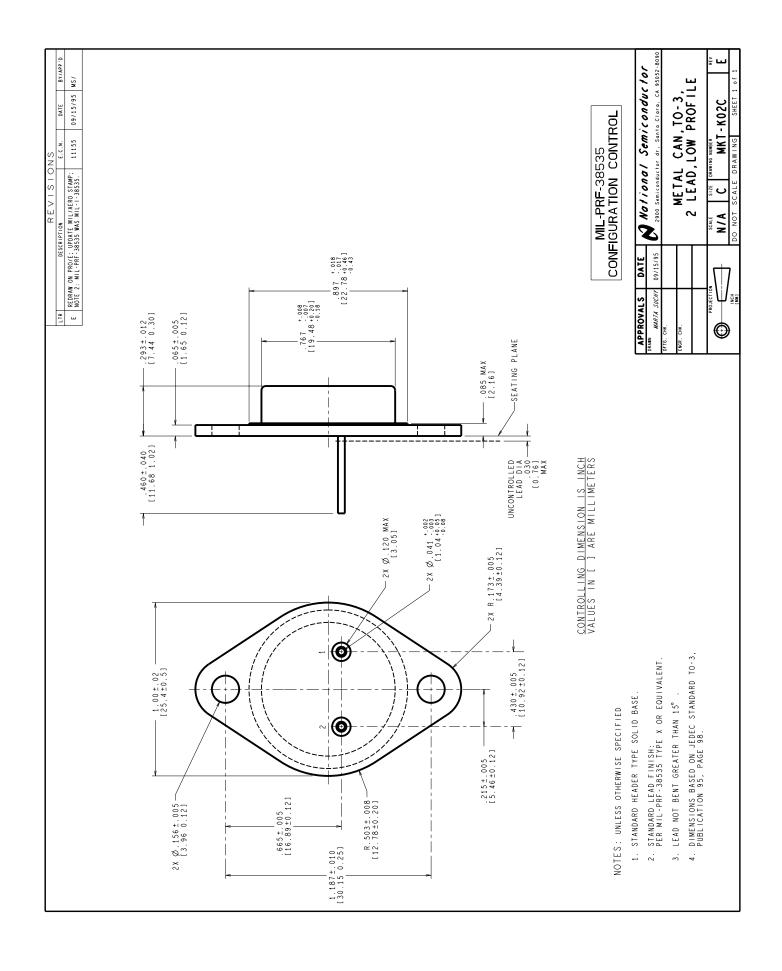
Note 1: Functional test only.

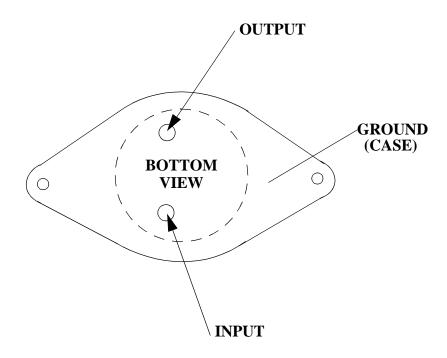
## Graphics and Diagrams

GRAPHICS#	DESCRIPTION
05826HRA2	METAL CAN (KA), TO-3, 2LD, LOW PROFILE (B/I CKT)
06332HRA2	CERDIP (J), 16 LEAD (B/I CKT)
06351HRA1	CERPACK (W), 16 LEAD (B/I CKT)
J16ARL	CERDIP (J), 16 LEAD (P/P DWG)
K02CRE	METAL CAN (KA), TO-3, 2LD, LOW PROFILE (P/P DWG)
P000137A	METAL CAN (KA), TO-3, 2LD, LOW PROFILE (PINOUT)
P000159A	CERDIP (J), 16 LEAD (PINOUT)
P000386A	CERAMIC SOIC (WG), 16 LEAD (PINOUT)
WG16ARC	CERAMIC SOIC (WG), 16 LEAD (P/P DWG)

See attached graphics following this page.

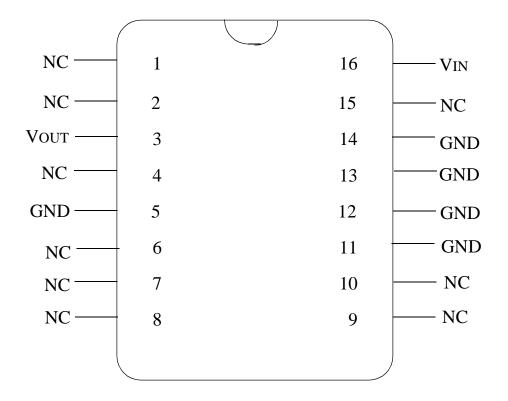






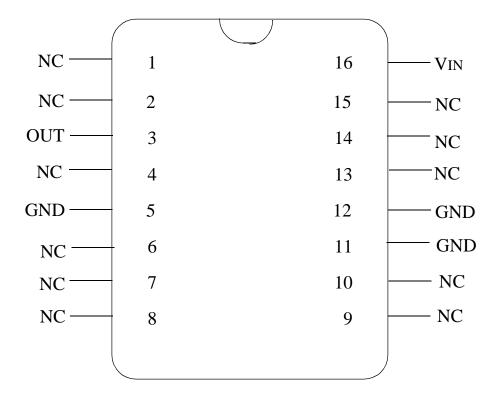
## LM2940K-XX/883 2 - LEAD TO3 CONNECTION DIAGRAM BOTTOM VIEW P000137A





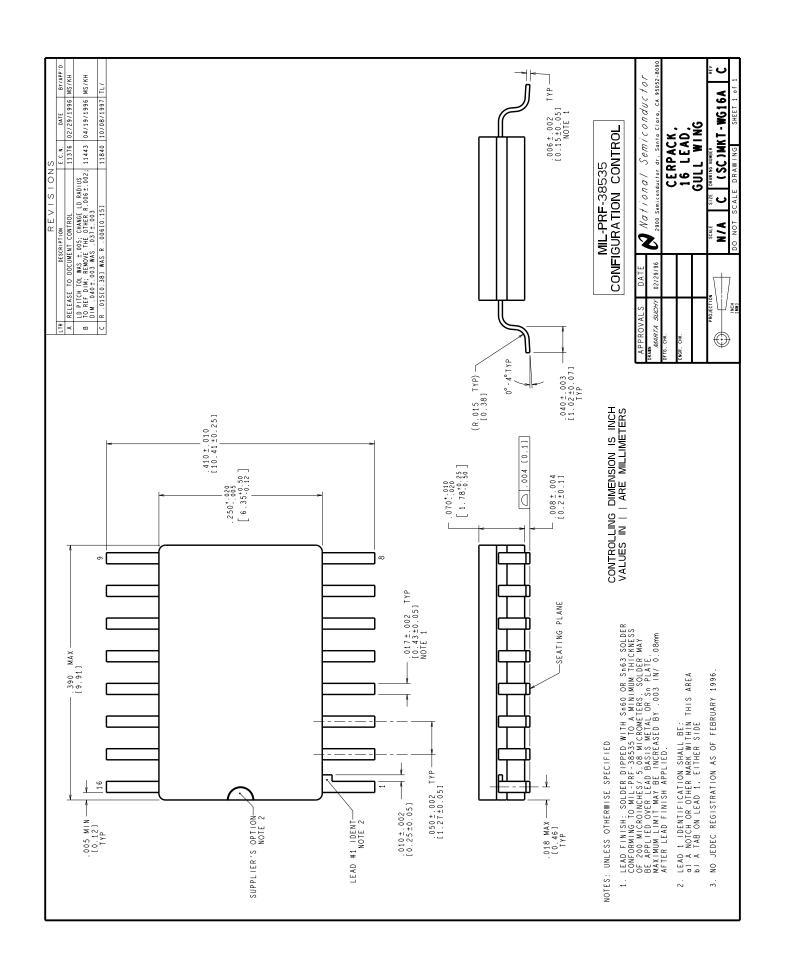
# LM2940J-XX 16 - LEAD DIP CONNECTION DIAGRAM TOP VIEW P000159A





# LM2940WG 16 - LEAD CERAMIC SOIC CONNECTION DIAGRAM TOP VIEW P000386A





## Revision History

Rev	ECN #	Rel Date	Originator	Changes
0A0	M0001534	12/15/98	Barbara Lopez	Initial Release of: MNLM2940-5.0-X Rev. 0A0. Added note for power dissipation and reference to thermal resistance for Aluminum Nitride package.
0B0	M0003110	02/03/99	Rose Malone	Update MDS: MNLM2940-5.0-X, Rev. 0A0 to MNLM2940-5.0-X, Rev. 0B0
0C1	M0003228	10/08/99	Rose Malone	Update MDS: MNLM2940-5.0-X, Rev. 0B0 to MNLM2940-5.0-X, Rev. 0C1.
1A1	M0003560	10/08/99	Rose Malone	Update MDS: MNLM2940-5.0-X, Rev. 0C1 to MNLM2940-5.0-X, Rev. 1A1. Updated Absolute Section Thermal Resistance temp. ThetaJa and ThetaJC to T03 package. Changed Vdo, Io = 100mA, Max. condition for subgroup 1 from 150mV to 200mV and subgroup 2 from 200mV to 300mV.